

KSC5242

Audio Power Amplifier

- High Current Capability : I_C=15A
 High Collector Breakdown Voltage : V_{CEO}=230V (Min.)
- High Power Dissipation
- Wide S.O.A
- Complement to KSA1962



NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings $T_C=25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage	230	V
V _{CEO}	Collector-Emitter Voltage	230	V
V _{EBO}	Emitter-Base Voltage	5	V
I _C	Collector Current(DC)	10	Α
IB	Base Current	1.5	Α
PC	Collector Dissipation (T _C =25°C)	100	W
TJ	Junction Temperature	150	°C
T _{STG}	Storage Temperature	- 50 ~ 150	°C

Electrical Characteristics $T_C=25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	I _C =5mA, I _E =0	230			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	I _C =10mA, R _{BE} =∞	230			V
BV _{EBO}	Emitter-Base Breakdown Voltage	$I_E=5mA$, $I_C=0$	5			V
I _{CBO}	Collector Cut-off Current	V_{CB} =230V, I_{E} =0			5.0	uA
I _{EBO}	Emitter Cut-off Current	V_{EB} =5V, I_{C} =0			5.0	uA
h _{FE1}	* DC Current Gain	V _{CE} =5V, I _C =1A	55		160	
h _{FE2}	DC Current Gain	V_{CE} =5V, I_{C} =7A	35	60		
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C =8A, I _B =0.8A		0.4	3.0	V
V _{BE} (on)	Base-Emitter ON Voltage	V_{CE} =5V, I_{C} =7A		1.0	1.5	V
f _T	Current Gain Bandwidth Product	V _{CE} =5V, I _C =1A		30		MHz
C _{ob}	Output Capacitance	V _{CB} =10V, f=1MHz		200		pF

* Pulse Test : PW=20us

h_{FE} Classification

Classification	R	0	
h _{FE1}	55 ~ 110	80 ~ 160	

Typical Characteristics

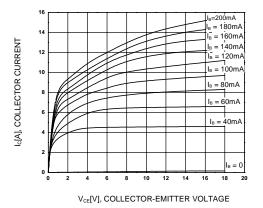


Figure 1. Static Characteristic

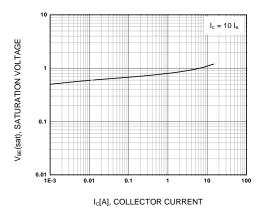


Figure 3. Base-Emitter Saturation Votlage

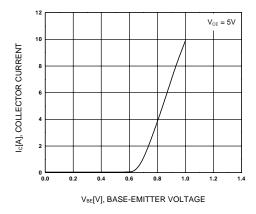


Figure 5. Base-Emitter On Voltage

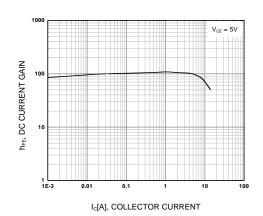


Figure 2. DC current Gain

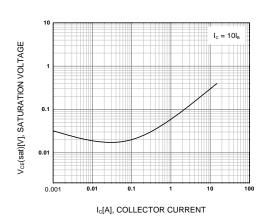
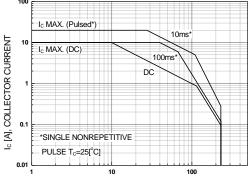


Figure 4. Collector-Emitter Saturation Voltage



 $V_{\text{CE}} \ [V], \ COLLECTOR\text{-}EMITTER \ VOLTAGE$

Figure 6. Safe Operating Area

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ypical Characteristics (Continued)

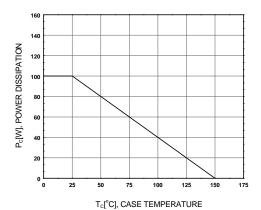


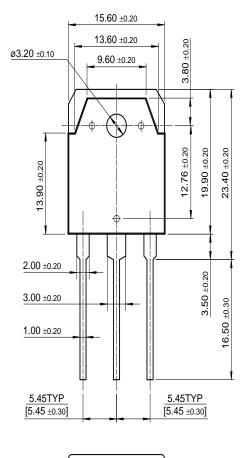
Figure 7. Power Derating

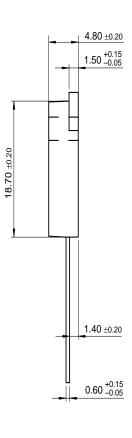
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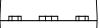
KSC5242

Package Demensions

TO-3P







Dimensions in Millimeters

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